Switching Transistor PNP Silicon

COLLECTOR 3 2 BASE 1 EMITTER

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCEO	-12	Vdc
Collector-Base Voltage	VCBO	-12	Vdc
Emitter-Base Voltage	V _{EBO}	-4.0	Vdc
Collector Current — Continuous	IC	-80	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{ heta JC}$	83.3	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	•			
Collector-Emitter Breakdown Voltage ($I_C = -100 \mu Adc$, $V_{BE} = 0$)	V(BR)CES	-12	_	Vdc
Collector-Emitter Sustaining Voltage ⁽¹⁾ $(I_C = -10 \text{ mAdc}, I_B = 0)$	VCEO(sus)	-12	_	Vdc
Collector–Base Breakdown Voltage (I _C = –100 μAdc, I _E = 0)	V(BR)CBO	-12	_	Vdc
Emitter-Base Breakdown Voltage ($I_E = -100 \mu Adc$, $I_C = 0$)	V(BR)EBO	-4.0	_	Vdc
Collector Cutoff Current $(V_{CE} = -6.0 \text{ Vdc}, V_{BE} = 0)$ $(V_{CE} = -6.0 \text{ Vdc}, V_{BE} = 0, T_{A} = 65^{\circ}\text{C})$	ICES	_ _	-0.01 -1.0	μAdc
Base Current $(V_{CE} = -6.0 \text{ Vdc}, V_{EB} = 0)$	lΒ	_	-10	nAdc

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

MPS3640





ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic			Min	Max	Unit
ON CHARACTERIS	STICS(1)			•	•
DC Current Gain ($I_C = -10 \text{ mAdc}$, $V_{CE} = -0.3 \text{ Vdc}$) ($I_C = -50 \text{ mAdc}$, $V_{CE} = -1.0 \text{ Vdc}$)			30 20	120 —	_
Collector-Emitter Saturation Voltage (I _C = -10 mAdc, I _B = -1.0 mAdc) (I _C = -50 mAdc, I _B = -5.0 mAdc) (I _C = -10 mAdc, I _B = -1.0 mAdc, T _A = 65°C)			_ _ _ _	-0.2 -0.6 -0.25	Vdc
Base-Emitter Saturation Voltage ($I_C = -10 \text{ mAdc}$, $I_B = -0.5 \text{ mAdc}$) ($I_C = -10 \text{ mAdc}$, $I_B = -1.0 \text{ mAdc}$) ($I_C = -50 \text{ mAdc}$, $I_B = -5.0 \text{ mAdc}$)		VBE(sat)	-0.75 -0.75 	-0.95 -1.0 -1.5	Vdc
SMALL-SIGNAL C	HARACTERISTICS				
Current-Gain — Bandwidth Product ($I_C = -10 \text{ mAdc}$, $V_{CE} = -5.0 \text{ Vdc}$, $f = 100 \text{ MHz}$)		fΤ	500	_	MHz
Output Capacitance (V _{CB} = -5.0 Vdc, I _E = 0, f = 1.0 MHz)		C _{obo}	_	3.5	pF
Input Capacitance (V _{EB} = -0.5 Vdc, I _C = 0, f = 1.0 MHz)			_	3.5	pF
SWITCHING CHAR	ACTERISTICS				
Delay Time	$(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -50 \text{ mAdc}, V_{BE(off)} = -1.9 \text{ Vdc},$	t _d	_	10	ns
Rise Time	$I_{B1} = -5.0 \text{ mAdc}$	t _r		30	ns
Storage Time	$(V_{CC} = -6.0 \text{ Vdc}, I_C = -50 \text{ mAdc}, I_{B1} = I_{B2} = -5.0 \text{ mAdc})$	t _S		20	ns
Fall Time	1	t _f		12	ns
Turn–On Time $(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -50 \text{ mAdc}, I_{B1} = -5.0 \text{ mAdc})$ $(V_{CC} = -1.5 \text{ Vdc}, I_{C} = -10 \text{ mAdc}, I_{B1} = -0.5 \text{ mAdc})$		ton	_ _	25 60	ns
Turn–Off Time $(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -50 \text{ mAdc}, I_{B1} = I_{B2} = -5.0 \text{ mAdc})$ $(V_{CC} = -1.5 \text{ Vdc}, I_{C} = -10 \text{ mAdc}, I_{B1} = I_{B2} = -0.5 \text{ mAdc})$		^t off	_ _	35 75	ns

^{1.} Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%.

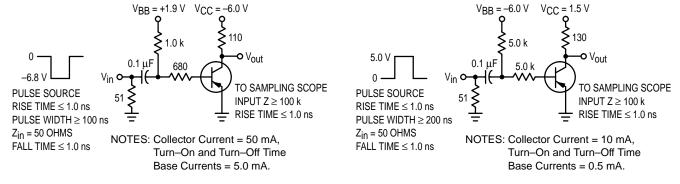


Figure 1. Figure 2.

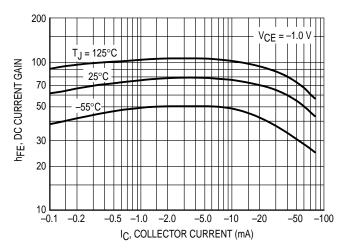


Figure 3. DC Current Gain

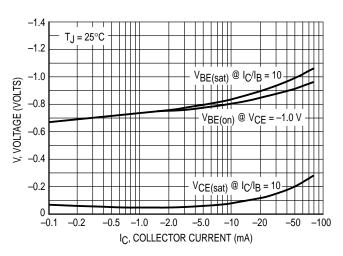


Figure 4. "On" Voltages

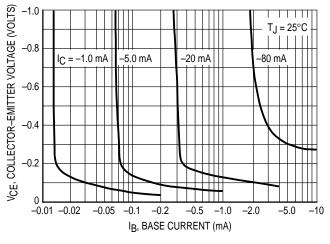


Figure 5. Collector Saturation Region

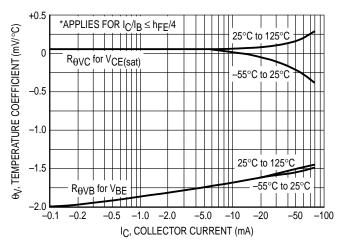


Figure 6. Temperature Coefficients

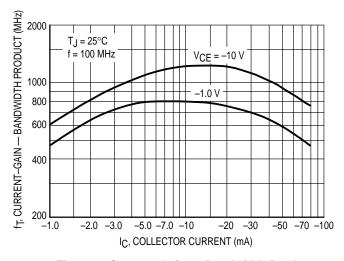


Figure 7. Current-Gain — Bandwidth Product

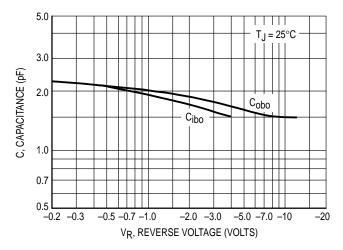
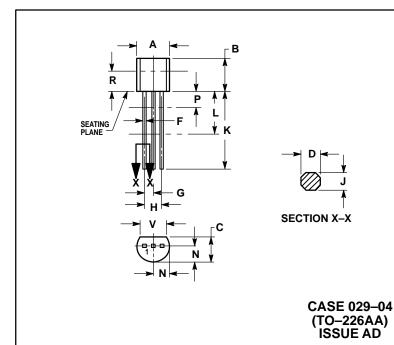


Figure 8. Capacitance

PACKAGE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K
 MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.022	0.41	0.55	
F	0.016	0.019	0.41	0.48	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
٧	0.135	_	3.43		

STYLE 1: PIN 1. EMITTER BASE

COLLECTOR

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